Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-235-3304

Inclosure Mate	
Glass	
Overall Length	:
0.200 inches	
Terminal Lengt	h:
1.500 inches	
Overall Diamet	er:
0.090 inches	
Joint Electronie	c Device Engineering Council/jedec/case Outline Designation:
Do-35	
Mounting Meth	od:
Terminal	
Features Provi	ded:
Hermetically sea	aled case and quality assurance level s
Semiconductor	r Material:
Silicon	
Voltage Rating	In Volts Per Characteristic:
20.0 regulator	voltage
Voltage Tolerai	nce In Percent:
-5.0/+5.0	
Current Rating	Per Characteristic:
21.00 milliampe	res repetitive peak forward current
Power Rating F	Per Characteristic:
500.0 milliwatts	small-signal input power, common-collector preset
Maximum Oper	ating Tempurature Per Measurement Point:
200.0 degrees c	elsius ambient air
Test Data Docu	iment:
81349-mil-s-195	i00 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specificatio
format; exclude	s commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental a	nd performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type	And Quantity:
2 uninsulated wi	ire lead
Specification D	ata:
81349-mil-s-195	i00/533 government specification
Shelf Life:	
N/a	
Unit Of Measur	e:
Demilitarizatior	1:
No	
Fiig:	
A110a0	